



## High-Speed, Low R<sub>ON</sub>, SPDT Analog Switch

(2:1 Multiplexer/Demultiplexer Bus Switch)

#### **DESCRIPTION**

The DG3157 is a high-speed single-pole double-throw, low power, TTL-Compatible bus switch. Using sub-micro CMOS technology, the DG3157 achieves low on-resistance and negligible propagation delay.

The DG3157 can handle both analog and digital signals and permits signals with amplitudes of up to  $V_{CC}$  to be transmitted in either direction.

When the Select pin is low,  $B_0$  is connected to the output A pin. When the Select pin is high,  $B_1$  is connected to the output A pin. The path that is open will have a high-impedance state with respect to the output. Make-before-break is guaranteed. An eptiaxial layer prevents latch-up.

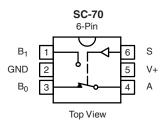
#### **FEATURES**

- Halogen-free According to IEC 61249-2-21
- Direct cross to industry standard SN74LVC1G3157, NC7SB3157, NLASB3175, PI5A3157, and STG3157
- SC-70 6-lead package
- 1.65 V to 5.5 V V<sub>CC</sub> operation
- 5 Ω connection between ports
- Minimal propagation delay
- · Break-before-make switching
- Zero bounce in flow-through mode



ROHS COMPLIANT HALOGEN FREE

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



Device Marking: G1

TRUTH TABLE	
Logic Input (S)	Function
0	B <sub>0</sub> Connected to A
1	B <sub>1</sub> Connected to A

ORDERING INFORMATION						
Temp. Range	Package	Part Number				
- 40 °C to 85 °C	SC-70-6	DG3157DL-T1-E3 DG3157DL-T1-GE3 (Halogen-free)				

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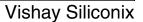


ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Reference V+ to GND		- 0.3 to + 6				
S, A, B <sup>a</sup>		- 0.3 to (V+ + 0.3)	- V			
Continuous Current (Any terminal)		± 50	m A			
Peak Current (Pulsed at 1 ms, 10 % duty c	ycle)	± 200	- mA			
Storage Temperature	D Suffix	- 65 to 150	°C			
Power Dissipation (Packages) <sup>b</sup>	6-Pin SC-70 <sup>c</sup>	250	mW			

#### Notes:

- a. Signals on A, or B or S exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 3.1 mW/°C above 70 °C.

SPECIFICATIONS								
		Test Conditions Unless Otherwise Specified $V+=3.0 \text{ V, } V_S=0.25 \text{ V to } 0.7 \text{ V+}^e$			- 4	Limits - 40 °C to 85 °C		
Parameter	Symbol			Temp.a	Min.b	Typ. <sup>c</sup>	Max.b	Unit
DC Characteristics							•	
High Level Input Voltage	V <sub>SH</sub>	V+ =	1.65 to 1.95 V	Full	0.75 V+			
riigii Level iliput voltage	*511	V+ :	= 2.3 to 5.5 V	Full	0.7 V+			V
Low Level Input Voltage	$V_{SI}$		1.65 to 1.95 V	Full			0.25 V+	<b>'</b>
Low Level input voltage	- SL	V+ :	= 2.3 to 5.5 V	Full			0.3 V+	
			$V_{BN} = 0 \text{ V}, I_{A} = 30 \text{ mA}$	Full		6	7	
		V+ = 4.5 V	$V_{BN} = 2.3 \text{ V}, I_{A} = -30 \text{ mA}$	Full		6	12	
			$V_{BN} = 4.5 \text{ V}, I_{A} = -30 \text{ mA}$	Full		9	15	
	R <sub>ON</sub>	V+ = 3.0 V	$V_{BN} = 0 \text{ V}, I_{A} = 24 \text{ mA}$	Full		8	9	
On Resistance			$V_{BN} = 3.0 \text{ V}, I_{A} = -24 \text{ mA}$	Full		12	20	
		V+ = 2.3 V	$V_{BN} = 0 \text{ V}, I_{A} = 8 \text{ mA}$	Full		9	12	Ω
			$V_{BN} = 2.3 \text{ V}, I_A = -8 \text{ mA}$	Full		13	30	
		V+ = 1.65 V	$V_{BN} = 0 \text{ V}, I_{A} = 4 \text{ mA}$	Full		12	20	
			V <sub>BN</sub> = 1.8 V, I <sub>A</sub> = - 4 mA	Full		18	50	
	R <sub>FLAT</sub>	0 < V <sub>BN</sub> < V+	$V+ = 4.5 \text{ V}, I_A = -30 \text{ mA}$	Room		6		
On Desistance Flateres			V+ = 3.0 V, I <sub>A</sub> = - 24 mA	Room		12		1
On Resistance Flatness			V+ = 2.3 V, I <sub>A</sub> = - 8 mA	Room		22		
			V+ = 1.65 V, I <sub>A</sub> = - 4 mA	Room		90		
	ΔR <sub>ON</sub>	V+ = 4.5 V, V <sub>BN</sub> = 3.15 V, I <sub>A</sub> = - 30 mA		Room		0.32		
On Resistance Matching Between Channels		$V+ = 3.0 \text{ V}, V_{BN} = 2.1 \text{ V}, I_{A} = -24 \text{ mA}$		Room		0.31		
		$V+ = 2.3 \text{ V}, V_{BN} = 1.6 \text{ V}, I_{A} = -8 \text{ mA}$		Room		0.30		
		$V+ = 1.65 \text{ V}, V_{BN} = 1.15 \text{ V}, I_{A} = -4 \text{ mA}$		Room		0.29		
Input Leakage Current	I <sub>S</sub>	V+ = 5.5 V, V <sub>A</sub> = 5.5 V		Room Full	- 0.1 - 1.0		0.1 - 1.0	
Off Stage Switch Leakage	I <sub>BN(off)</sub>	V+ = 5.5 V, V <sub>A</sub> /V <sub>B</sub> = 0 V/5.5 V		Room Full	- 0.1 - 1.0		0.1 - 1.0	μΑ
On State Switch Leakage	I <sub>BN(on)</sub>	V+ = 5.5 \	$V_{A}/V_{B} = 0 \text{ V}/5.5 \text{ V}$	Room	- 0.1 - 1.0		0.1	





	Test Conditions Unless Otherwise Specified				<b>Limits</b> - 40 °C to 85 °C			
Parameter	Symbol	$V+ = 3.0 V, V_S = 0$	Temp.a	Min.b	Typ.c	Max.b	Unit	
Power Supply	•							
Power Supply Range	V+			Full	1.65		5.5	V
Quiescent Supply Current	l+	$V+ = 5.5 V, V_A = V$	/ <sub>B</sub> = V+ or GND	Room Full			1 10	μΑ
<b>AC Electrical Characteristice</b>	•							
			V+ = 1.65 to 1.95 V	Full				
Day Dalay Tar f	t <sub>PHL</sub> /t <sub>PLH</sub>	V <sub>A</sub> = 0 V	V+ = 2.3 to 2.7 V	Full		1.2		1
Prop Delay Time <sup>f</sup>	PHL/PLH	V <sub>A</sub> – 0 V	V+ = 3.0 to 3.6 V	Full		0.8		
			V+ = 4.5 to 5.5 V	Full		0.3		
			V+ = 1.65 to 1.95 V	Room Full		10.2 10.4		
0 f	t <sub>PZL</sub> /t <sub>PZH</sub>	$V_{LOAD} = 2 \times V + \text{ for } t_{PZL}$	V+ = 2.3 to 2.7 V	Room Full		5.9 6.2		
Output Enable Time <sup>†</sup>	'PZL/'PZH	$V_{LOAD} = 0 \text{ V for } t_{PZH}$	V+ = 3.0 to 3.6 V	Room Full		4.1 4.5		
			V+ = 4.5 to 5.5 V	Room Full		2.6 2.9		
		$V_{LOAD} = 2 \times V + \text{ for } t_{PLZ}$ $V_{LOAD} = 0 \text{ V for } t_{PHZ}$	V+ = 1.65 to 1.95 V	Room Full		10.2 10.4		ns
,			V+ = 2.3 to 2.7 V	Room Full		5.9 6.2		
Output Disable Time <sup>f</sup>	t <sub>PLZ</sub> /t <sub>PHZ</sub>		V+ = 3.0 to 3.6 V	Room Full		4.1 4.5		
			V+ = 4.5 to 5.5 V	Room Full		2.6 2.9		
		V+ = 1.65 to 1.95 V		Full	0.5			1
d		V+ = 2.3 to 2.7 V		Full	0.5			1
Break-Before-Make Time <sup>d</sup>	t <sub>BBM</sub>	V+ = 3.0 to 3.65		Full	0.5			1
		V+ = 4.5 to 5.5 V		Full	0.5			1
O d	Q	$C_L = 0.1 \text{ nF}, V_{GEN} = 0 \text{ V}$	V+ = 5 V	Room		7		
Charge Injection <sup>d</sup>	Q	$R_{GEN} = 0 \Omega$	V+ = 3.3 V	Room		3		рC
Analog Switch Characteristic	s							
Off Isolation <sup>d</sup>	OIRR	$R_L = 50 \Omega$ , f	- 10 MHz	Room		- 57.6		٩D
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	nL = 50 12, 1	- IO IVII IZ	Room		- 58.7		dB
- 3 db Bandwidth <sup>d</sup>	BW	$R_L = 50 \Omega$		Room		> 250		MH
Capacitance								
Control Pin Capacitance <sup>d</sup>	C <sub>IN</sub>	V+ = 0 V		Room		4.9		
B Port Off Capacitance <sup>d</sup>	C <sub>IO-B</sub>			Room		< 6.5		
A Port Capacitance When Switch Enable <sup>d</sup>	C <sub>IO-A(on)</sub>	V+ =	5 V	Room		< 18.5		pF

#### Notes:

- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V<sub>IN</sub> = input voltage to perform proper function.
- f. Guaranteed by design and not production tested. The bus switch propagation delay is a function of the RC time constant contributed by the on-resistance and the specified load capacitance with an ideal voltage source (zero output impedance) driving the switch.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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## **LOGIC DIAGRAM** Positive Logic

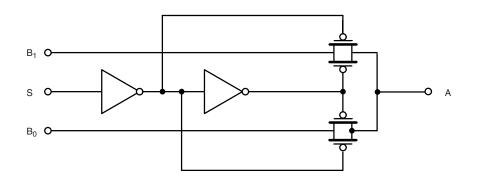
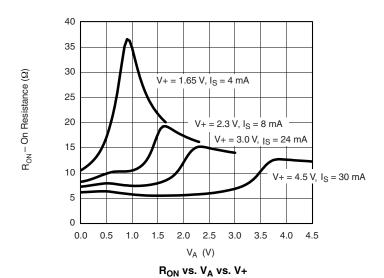


Figure 1.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





#### **AC LOADING AND WAVEFORMS**

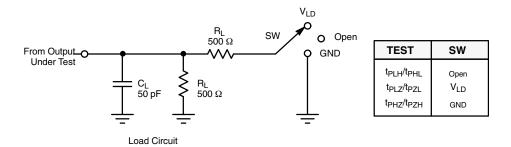


Figure 2. AC Test Circuit

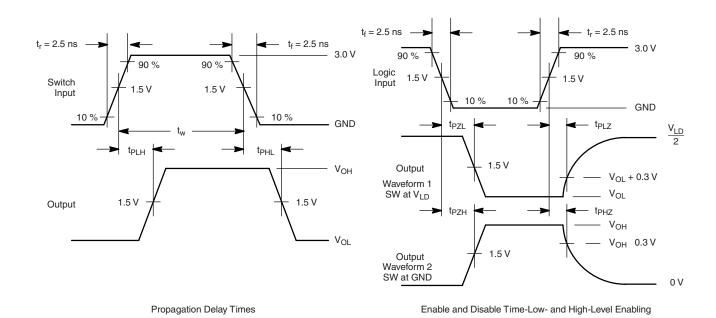


Figure 3. AC Waveforms

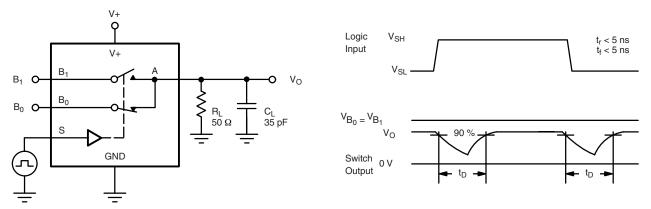
#### Notes

- $\bullet$   $\mathbf{C}_{\mathsf{L}}$  includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ .
- The outputs are measured one at a time with one transition per measurement.
- t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- $\bullet$   $t_{\mbox{\scriptsize PZL}}$  and  $t_{\mbox{\scriptsize PZH}}$  are the same as  $t_{\mbox{\scriptsize dis}}.$
- $\bullet$   $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{dis}}.$
- V<sub>LD</sub> = 2 V+.

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#### **TEST CIRCUITS**



C<sub>L</sub> (includes fixture and stray capacitance)

Figure 4. Break-Before-Make Interval

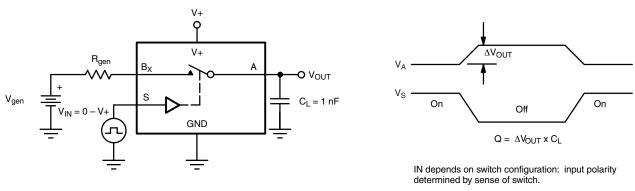


Figure 5. Charge Injection

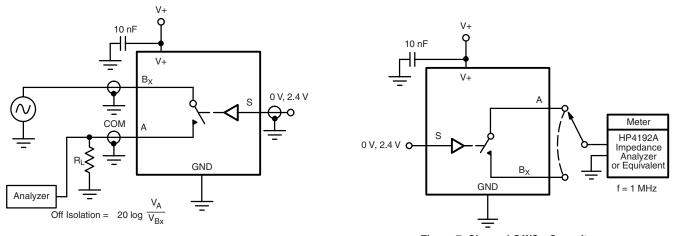


Figure 6. Off-Isolation

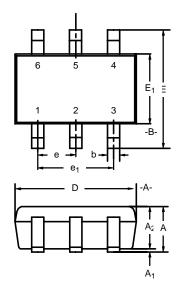
Figure 7. Channel Off/On Capacitance

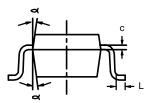
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#### SC-70: 6-LEADS





	MIL	LIMET	ERS	INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.90	_	1.10	0.035	_	0.043
A <sub>1</sub>	-	_	0.10	-	_	0.004
A <sub>2</sub>	0.80	_	1.00	0.031	_	0.039
b	0.15	_	0.30	0.006	_	0.012
С	0.10	-	0.25	0.004	-	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
Ε	1.80	2.10	2.40	0.071	0.083	0.094
E <sub>1</sub>	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65BSC				0.026BSC	;
e <sub>1</sub>	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
کے		7°Nom			7°Nom	

DWG: 5550



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PI5A3166TAEX FSA634UCX TC4066BP(N,F) DG302BDJ-E3 PI5A100QEX HV2605FG-G HV2301FG-G RS2117YUTQK10
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NLAS4599DFT2G NLAST4599DFT2G NLAST4599DTT1G DG300BDJ-E3 DG2503DB-T2-GE1 DG2502DB-T2-GE1
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